<u>TOSHIBA</u>

TOSHIBA Photocoupler GaAs Ired + Photo-Triac

TLP166J

Triac Drive Programmable Controllers AC-Output Module Solid State Relay

The TOSHIBA mini flat coupler TLP166J is a small outline coupler, suitable for surface mount assembly. The TLP166J consists of a photo triac, optically coupled to a gallium arsenide infrared emitting diode.

- Peak off-state voltage: 600V(min.)
- Trigger LED current: 10mA(max.)
- On-state current: 70mA(max.)
- Isolation voltage: 2500Vrms(min.)
- UL recognized: UL1577, file no. E67349
- Option(V4) type
 VDE approved: EN 60747-5-2 satisfied
 Maximum operating insulation voltage: 565Vpk
 Highest permissible over voltage: 4000Vpk

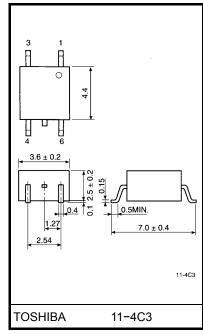
Trigger LED Current

Type (Note 1)	00	Current (mA) Ta=25°C	Marking Of
	Min.	Max.	Classification
(IFT7)	_	7	Т7
None		10	T7, blank

* Exp. IFT7: TLP166J(IFT7)

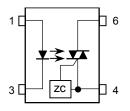
(Note 1): Application type name for certification test, please use standard product type name, i.e.

TLP166J(IFT7): TLP166J



Weight: 0.09 g

Pin Configurations



- 1. Anode
- 3. Cathode
- Terminal 1
 Terminal 2

Unit in mm

Absolute Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
	Forward current	١ _F	50	mA		
	Forward current derating (Ta ≥ \$	ΔI _F / °C	-0.7	mA / °C		
LED	Peak forward current (100µs pu	lse, 100pps)	I _{FP}	1	А	
	Reverse voltage	V _R	5	V		
	Junction temperature	Tj	125	°C		
	Off-state output terminal voltage	V _{DRM}	600	V		
	On-state RMS Current	Ta=25°C		70	mA	
Detector		Ta=70°C	I _{T(RMS)}	40	ma	
	On–state current derating(Ta ≥	ΔI _T / °C	-0.67	mA / °C		
	Peak on-state current (100µs p	I _{TP}	2	A		
	Peak nonrepetitive surge curren (PW=10ms, DC=10%)	ITSM	1.2	А		
	Junction temperature	Tj	115	°C		
Storage temperature range			T _{stg}	-55~125	°C	
Operating temperature range			T _{opr}	-40~100	°C	
Lead soldering temperature (10s)			T _{sol}	260	°C	
Isolation voltage (AC, 1min., R.H.≤ 60%) (Note 2)			BVS	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 2): Device considered a two terminal device: Pins 1 and 3 shorted together and 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	_	_	240	Vac
Forward current	١ _F	15	20	25	mA
Peak on-state current	I _{TP}	_	-	1	А
Operating temperature	T _{opr}	-25		85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

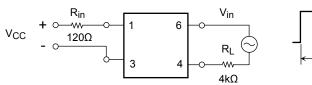
Electrical Characteristics (Ta = 25°C)

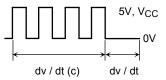
	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V _F	I _F =10mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R =5 V	_	_	10	μA
	Capacitance	CT	V=0, f=1MHz	—	30	_	pF
	Peak off-state current	IDRM	V _{DRM} =600V	—	30	1000	nA
	Peak on-state voltage	V _{TM}	I _{TM} =70mA	—	1.7	2.8	V
ctor	Holding current	Ι _Η	—	—	0.6		mA
Detector	Critical rate of rise of off-state voltage	dv / dt	V _{in} =240Vrms, Ta=85°C (Note 3)	200	500		V / µs
	Critical rate of rise of commutating voltage	dv / dt(c)	I _T =15mA, V _{in} =60Vrms (Note 3)	_	0.2	_	V / µs

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V _T =6V	_	_	10	mA
Inhibit voltage	VIH	I _F =rated I _{FT}	—	_	50	V
Leakage in inhibited state	Ιн	I _F =rated I _{FT} V _T =rated V _{DRM}	—		600	μA
Capacitance input to output	CS	V _S =0, f=1MHz	—	0.8	_	pF
Isolation resistance	R _S	V _S =500V, R.H.≤ 60%	1×10 ¹²	10 ¹⁴	-	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation voltage	BVS	AC, 1 second, in oil	_	5000	_	VIIIS
		DC, 1 minute, in oil	_	5000	_	Vdc

(Note 3): dv / dt Test circuit





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20070701-EN

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